

SS32C THRU SS320C

Reverse Voltage - 20 to 200 Volts Forward Current - 3.0 Ampere

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

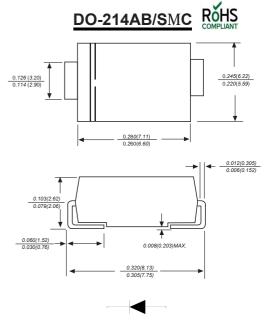
- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed:
 250 °C/10 seconds at terminals

Mechanical Data

Case: JEDEC DO-214AB/SMC molded plastic body Terminals: Solderable per MIL-STD-750,Method 2026 Polarity: Color band denotes cathode end Mounting

Position: Any

Weight: 0.0077 ounce, 0.22 grams



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	OVMDOLO	S MDD SS32C	MDD	MDD	MDD	MDD	MDD	MDD	MDD	MDD	
Marking Code	SYMBOLS		SS33C	SS34C	SS35C	SS36C	SS38C	SS310C	SS3150C	SS320C	UNITS
Maximum repetitive peak reverse voltage	Vrrm	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	VRMS	14	21	28	35	42	56	70	105	140	V
Maximum DC blocking voltage	VDC	20	30	40	50	60	80	100	150	200	V
Maximum average forward rectified current	l(AV)	3.0						Α			
Peak forward surge current											
8.3ms single half sine-wave	IFSM	80									A
superimposed onrated load (JEDEC Method)											
Maximum instantaneous forward voltage at 3.0A	VF	0.55		0.7	0.70 0		0.85 0.9		95	V	
Maximum DC reverse current Ta=25°C		0.5					(0.3		_	
at rated DCblocking voltage T _A =100°C	lR	IR 5.0				3.0		mA			
Typical junction capacitance (NOTE 1)	Cı	450 350				pF					
Typical thermal resistance (NOTE 2)	Rθja	50					°C/W				
Operating junction temperature range	TJ	-55to +150					°C				
Storage temperature range	Тѕтс	-55 to +150					°C				

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C. 2.P.C.B. mounted with 2.0"x2.0" (5.0x5.0cm) copper pad areas

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Typical Characterisitics

Fig.1 Forward Current Derating Curve

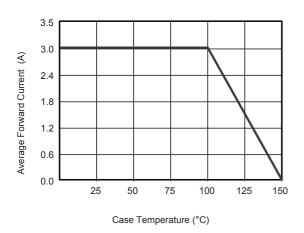
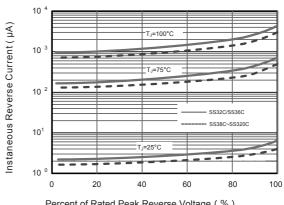


Fig.2 Typical Reverse Characteristics



Percent of Rated Peak Reverse Voltage (%)

Fig.3 Typical Forward Characteristic

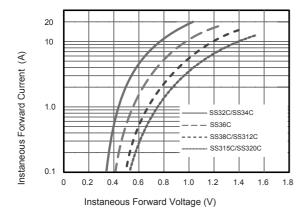


Fig.4 Typical Junction Capacitance

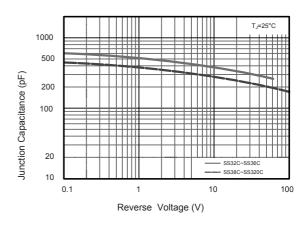


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current

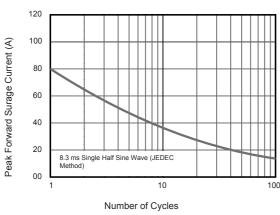
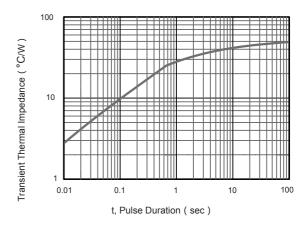


Fig.6- Typical Transient Thermal Impedance



The curve above is for reference only.

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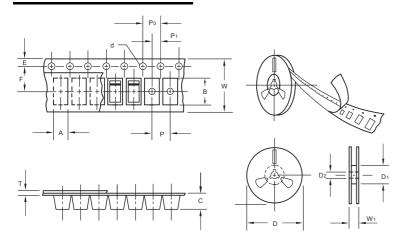
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Packing information

unit:mm

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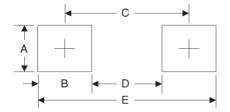
Item	Symbol	Tolerance	SMC		
Carrier width	Α	0.1	6.15		
Carrier length	В	0.1	8.41		
Carrier depth	С	0.1	2.42		
Sprocket hole	d	0.05	1.50		
13" Reel outside diameter	D	2.0	330.00		
13" Reel inner diameter	D1	min	50.00		
Feed hole diameter	D2	0.5	13.00		
Sprocket hole position	Е	0.1	1.75		
Punch hole position	F	0.1	7.50		
Punch hole pitch	Р	0.1	8.00		
Sprocket hole pitch	P ₀	0.1	4.00		
Embossment center	P1	0.1	2.00		
Overall tape thickness	Т	0.1	0.25		
Tape width	W	0.3	16.00		
Reel width	W1	1.0	16.50		

Note: Devices are packed in accordance with EIA standar RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (mm)	BOX (pcs)	INNER BOX (mm)	REEL DIA, (mm)	CARTON SIZE (mm)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMC	13"	3,000	4.0	6000	190*190*41	330	365*365*340	42000	14.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)		
Α	4.3	0.170		
В	4.1	0.160		
С	7.9	0.311		
D	3.8	0.150		
Е	12	0.472		

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